# NSN 5961-00-431-6830

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#### **Inclosure Material:**

Metal

**Overall Length:** 

1.573 inches

# **Overall Height:**

0.350 inches

**Overall Width:** 

1.050 inches

#### **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

40.0 breakdown voltage, collector-to-emitter, base open and 1.0 collector to emitter saturation voltage

# **Current Rating Per Characteristic:**

30.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

150.0 watts small-signal input power, common-collector absolute

#### **Transfer Ratio:**

20.0 static forward current transfer ratio, common-emitter and 120.0 static forward current transfer ratio, common-emitter

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

2 pin and 1 case

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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